

## MBR2090CT-M3, MBR20100CT-M3

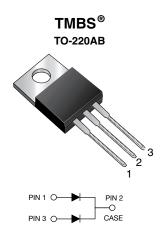
Vishay General Semiconductor

COMPLIANT

HALOGEN

**FREE** 

# **Dual High Voltage Trench MOS Barrier Schottky Rectifier**



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 10 A			
V <sub>RRM</sub>	90 V, 100 V			
I <sub>FSM</sub>	150 A			
V <sub>F</sub>	0.65 V			
T <sub>J</sub> max.	150 °C			
Package	TO-220AB			
Diode variation	Common cathode			

#### **FEATURES**

- Trench MOS Schottky technology
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

#### **TYPICAL APPLICATIONS**

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application.

### **MECHANICAL DATA**

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and

commercial grade

**Terminals:** Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

PARAMETER		SYMBOL	MBR2090CT	MBR20100CT	UNIT
Max. repetitive peak reverse voltage		$V_{RRM}$	90	100	V
Working peak reverse voltage		V <sub>RWM</sub>	90	100	V
Max. DC blocking voltage		$V_{DC}$	90	100	V
Max. average forward rectified current at T <sub>C</sub> = 133 °C	total device	1	20 10		А
	per diode	I <sub>F(AV)</sub>			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	150		А
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000		V/µs
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-65 to +150		°C

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT	
	I <sub>E</sub> = 10 A	T <sub>C</sub> = 25 °C		0.80		
Max. instantaneous forward voltage per diode	I <sub>F</sub> = IUA	T <sub>C</sub> = 125 °C	V <sub>F</sub> <sup>(1)</sup>	0.65	V	
	I <sub>F</sub> = 20 A			0.75		
Max. reverse current per diode		T <sub>J</sub> = 25 °C	[_ (2)	100	μΑ	
at working peak reverse voltage		T <sub>J</sub> = 100 °C		6.0	mA	

#### **Notes**

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS						
PARAMETER	UNIT					
Typical thermal registance per diede	$R_{ hetaJA}$	60	°C/W			
Typical thermal resistance per diode	$R_{ heta JC}$	2.0	C/VV			

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR20100CT-M3/4W	1.88	4W	50/tube	Tube		

### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

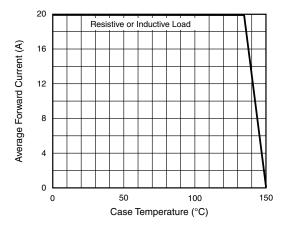


Fig. 1 - Forward Current Derating Curve

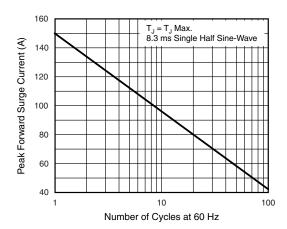


Fig. 2 - Max. Non-Repetitive Peak Forward Surge Current Per Diode

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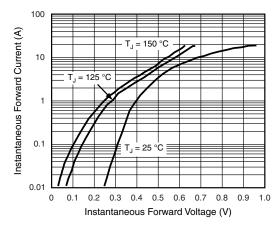
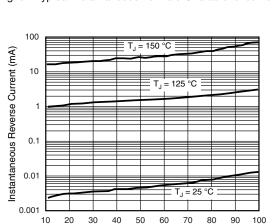


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode



Percent of Rated Peak Reverse Voltage (%)
Fig. 4 - Typical Reverse Characteristics Per Diode

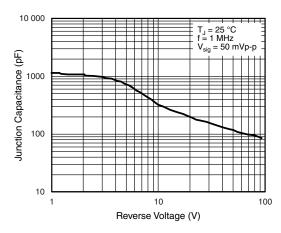


Fig. 5 - Typical Junction Capacitance Per Diode

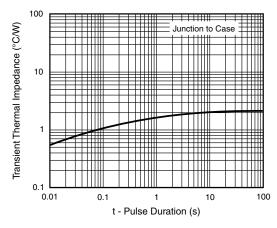
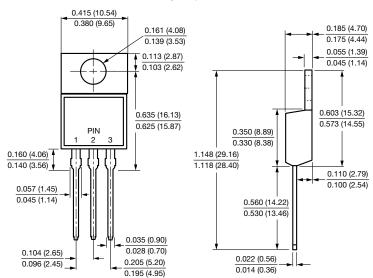


Fig. 6 - Typical Transient Thermal Impedance Per Diode

### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

### TO-220AB





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